

L Number	Hits	Search Text	DB	Time stamp
1	3	"09/986742"	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/08/05 11:52
2	1	("5327290").PN.	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/08/05 11:35
3	1	("5357290").PN.	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/08/05 11:48
4	38946	tft or (thin adj film adj transistor)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/08/05 11:48
5	18	(tft or (thin adj film adj transistor)) and (cross adj arrangement)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/08/05 11:49
6	751	(tft or (thin adj film adj transistor)) and (crystal\$ near4 variation)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/08/05 11:53
7	122	((tft or (thin adj film adj transistor)) and (crystal\$ near4 variation)) and layout	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/08/05 11:54
-	4347	((257/72,66,70) or (438/151,157,283) or (349/139)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/08/05 11:07
-	30120	thin adj film adj transistor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/19 13:14
-	319	(thin adj film adj transistor) and (gate adj length)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/19 13:15
-	130	((thin adj film adj transistor) and (gate adj length)) and (gate adj width)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/19 13:15
-	176	((((257/72,66,70) or (438/151,157,283) or (349/139)).CCLS.) and (gate adj length)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/19 13:15
-	56	(((((257/72,66,70) or (438/151,157,283) or (349/139)).CCLS.) and (gate adj length)) and (gate adj width)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/19 13:15

-	158	((thin adj film adj transistor) and (gate adj length)) and (gate adj width)) or (((257/72,66,70) or (438/151,157,283) or (349/139)).CCLS.) and (gate adj length)) and (gate adj width))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/19 13:15
-	16386	((current adj mirror) or (differential)) adj circuit	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/08/04 16:17
-	280	((current adj mirror) or (differential)) adj circuit) and ((thin adj film adj transistor) or tft)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/08/04 16:17
-	87	((current adj mirror) or (differential)) adj circuit) and ((thin adj film adj transistor) or tft)) and (gate with (length or width))	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/08/04 17:17
-	317	(257/500).CCLS.	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/08/04 17:19
-	8	((257/500).CCLS.) and ((thin adj film adj transistor) or tft)	USPAT; US-PGPUB; EPO; JPO; IBM_TDB	2004/08/04 17:20